

AAP Gen 7 (TO-240AA) Power Modules Schottky Rectifier, 110 A



AAP Gen 7 (TO-240AA)

PRIMARY CHARACTERISTICS			
I _{F(AV)}	110 A		
V _R	30 V		
Package	AAP Gen 7 (TO-240AA)		
Circuit configuration	Two diodes doubler circuit		

MECHANICAL DESCRIPTION

The AAP Gen 7, new generation of ADD-A-PAK module, combines the excellent thermal performances obtained by the usage of exposed direct bonded copper substrate, with advanced compact simple package solution and simplified internal structure with minimized number of interfaces.

FEATURES

- 150 °C T_J operation
- · Low forward voltage drop
- High frequency operation
- · Low thermal resistance
- UL approved file E78996



- · Designed and qualified for industrial level
- · Material categorization: for definitions of compliance please see www.vishav.com/doc?99912

BENEFITS

- Excellent thermal performances obtained by the usage of exposed direct bonded copper substrate
- High surge capability
- Easy mounting on heatsink

ELECTRICAL DESCRIPTION / APPLICATIONS

The VS-VSKDS220.. Schottky rectifier doubler has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature.

Typical applications are in high current switching power supplies, plating power supplies, UPS systems, converters, freewheeling diodes, welding, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS		
I _{F(AV)}	Rectangular waveform	110	А		
V _{RRM}		30	V		
I _{FSM}	t _p = 5 μs sine	18 000	А		
V _F	110 A _{pk} , T _J = 125 °C	0.57	V		
T_J	Range	-55 to +150	°C		

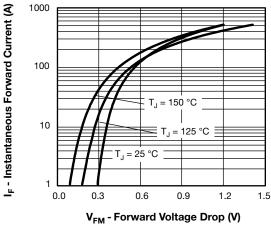
VOLTAGE RATINGS					
PARAMETER	SYMBOL	VS-VSKDS220/030	UNITS		
Maximum DC reverse voltage	V_{R}	30	V		
Maximum working peak reverse voltage	V_{RWM}	30	V		



ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current	I _{F(AV)}	_{V)} 50 % duty cycle at T _C = 110 °C, rectangular waveform		110	
Maximum peak one cycle	I _{FSM}	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated V _{RRM} applied	18 000	Α
non-repetitive surge current		10 ms sine or 6 ms rect. pulse		2000	
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 15 A, L = 1 mH		99	mJ
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		А	

ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum faminard valle and draw	V _{FM}	110 A	T _J = 25 °C	0.59	V
		220 A		0.78	
Maximum forward voltage drop		110 A	T _J = 125 °C	0.57	
		220 A		0.82	
Maximum vayayaa laakaga ayyyant		T _J = 25 °C	V _R = Rated V _R	10	mA
Maximum reverse leakage current	I _{RM}	T _J = 125 °C		650	IIIA
Maximum junction capacitance	C _T	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz), 25 °C		7400	pF
Typical series inductance	L _S	Measured lead to lead 5 mm from package body		7.0	nH
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs
Maximum RMS insulation voltage	V _{INS}	50 Hz		3000 (1 min) 3600 (1 s)	V

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and storage temperature range		T _J , T _{Stg}		-55 to +150	°C	
Maximum thermal resistance, junction to case per leg		R _{thJC}	DC operation	0.52	°C/W	
Typical thermal resistance, case to heatsink per module		R _{thCS}		0.1	C/VV	
Approximate weight				75	g	
Approximate weight				2.7	oz.	
Mounting torque ± 10 %	to heatsink		A mounting compound is recommended and the torque should be rechecked after a period of 3 h to allow for the	4	Nm	
.	busbar		spread of the compound.	3	14111	
Case style			JEDEC®	TO-240AA co	mpatible	





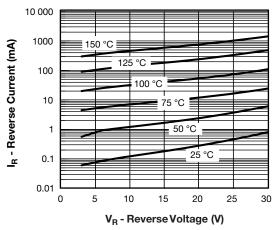


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

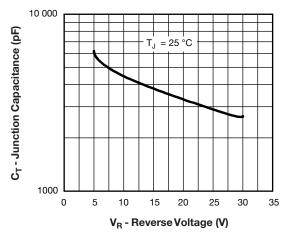


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

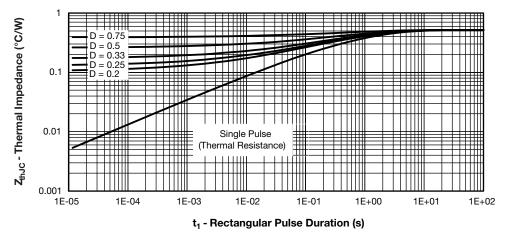


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

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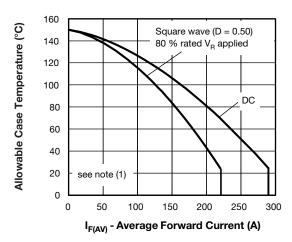


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

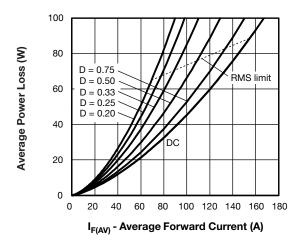


Fig. 6 - Forward Power Loss Characteristics

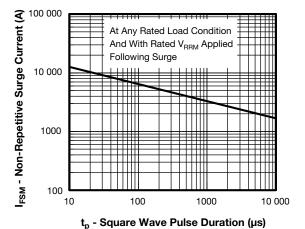


Fig. 7 - Maximum Non-Repetitive Surge Current

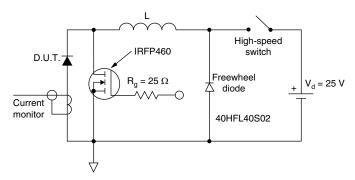


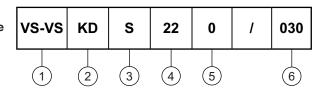
Fig. 8 - Unclamped Inductive Test Circuit

Note

 $^{(1)}$ Formula used: T_C = T_J - (Pd + Pd_{REV}) x R_{thJC}; Pd = forward power loss = I_{F(AV)} x V_{FM} at (I_{F(AV)}/D) (see fig. 6); Pd_{REV} = inverse power loss = V_{R1} x I_R (1 - D); I_R at V_{R1} = 80 % rated V_R

ORDERING INFORMATION TABLE

Device code



VS-VS = Vishay Semiconductors product

2 - Circuit configuration:

KD = ADD-A-PAK - 2 diodes doubler circuit

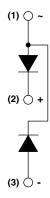
3 - S = Schottky diode

4 - Average rating (x 10)

Product silicon identification

6 - Voltage rating (030 = 30 V)

CIRCUIT CONFIGURATION



LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95369			



ADD-A-PAK Generation VII - Diode

DIMENSIONS in millimeters (inches)





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